# 74HC245; 74HCT245

Octal bus tranceiver; 3-state

Rev. 03 — 31 January 2005

**Product data sheet** 

#### 1. **General description**

The 74HC245; 74HCT245 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC245; 74HCT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74HC245; 74HCT245 features an output enable input  $(\overline{OE})$  for easy cascading and a send/receive input (DIR) for direction control.  $\overline{OE}$  controls the outputs so that the buses are effectively isolated.

The 74HC245; 74HCT245 is similar to the 74HC640; 74HCT640 but has true (non-inverting) outputs.

#### 2. **Features**

- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

#### **Quick reference data** 3.

**Quick reference data**  $GND = 0 \ V; \ T_{amb} = 25 \ ^{\circ}C; \ t_{r} = t_{f} = 6 \ ns.$ 

| Symbol                              | Parameter   | Conditions                                       | Min          | Тур | Max | Unit |
|-------------------------------------|---|--|--------------|-----|-----|------|
| Type 74H0                           | C245  |  |              |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay<br>An to Bn or Bn to An           | $C_L = 15 \text{ pF};$<br>$V_{CC} = 5 \text{ V}$ | -            | 7   | -   | ns   |
| Cı                                  | input capacitance                                   |  | -            | 3.5 | -   | pF   |
| C <sub>I/O</sub>                    | input/output capacitance                            |  | -            | 10  | -   | pF   |
| C <sub>PD</sub>                     | power dissipation<br>capacitance per<br>transceiver | $V_I = GND$ to $V_{CC}$                          | <u>[1]</u> - | 30  | -   | pF   |
| Type 74H0                           | CT245   |  |              |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay<br>An to Bn or Bn to An           | $C_L = 15 \text{ pF};$<br>$V_{CC} = 5 \text{ V}$ | -            | 10  | -   | ns   |



 Table 1:
 Quick reference data ...continued

 $GND = 0 \ V; \ T_{amb} = 25 \ ^{\circ}C; \ t_r = t_f = 6 \ ns.$ 

| Symbol           | Parameter   | Conditions                      | Min          | Тур | Max | Unit |
|------------------|---|---------------------------------|--------------|-----|-----|------|
| Cı               | input capacitance                                   |                                 | -            | 3.5 | -   | pF   |
| C <sub>I/O</sub> | input/output capacitance                            |                                 | -            | 10  | -   | pF   |
| C <sub>PD</sub>  | power dissipation<br>capacitance per<br>transceiver | $V_I = GND$ to $V_{CC} - 1.5 V$ | <u>[1]</u> - | 30  | -   | pF   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum{(C_L \times V_{CC}{}^2 \times f_o)}$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

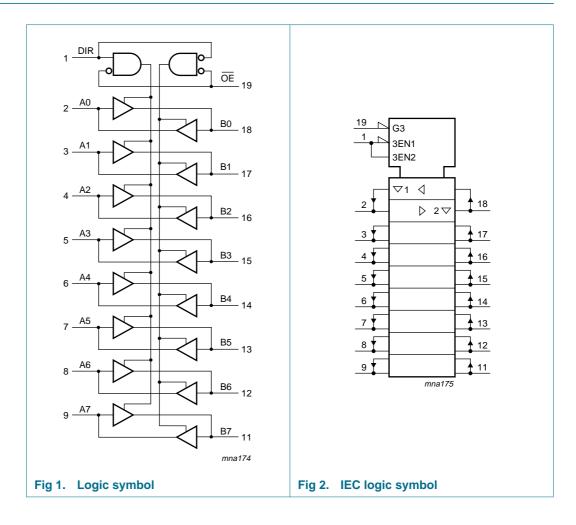
 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

## 4. Ordering information

### **Table 2: Ordering information**

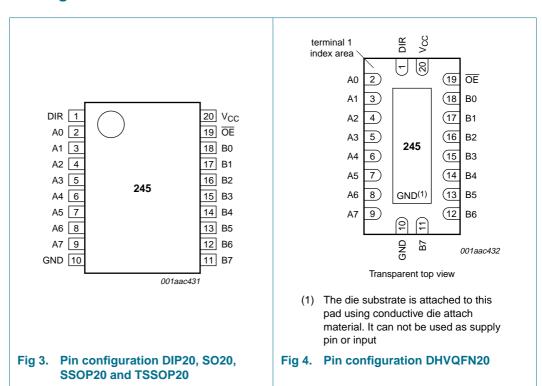
| Type number | Package           |          |   |          |  |  |  |
|-------------|-------------------|----------|---|----------|--|--|--|
|             | Temperature range | Name     | Description   | Version  |  |  |  |
| 74HC245N    | –40 °C to +125 °C | DIP20    | plastic dual in-line package; 20 leads (300 mil)  | SOT146-1 |  |  |  |
| 74HC245D    | –40 °C to +125 °C | SO20     | plastic small outline package; 20 leads;<br>body width 7.5 mm   | SOT163-1 |  |  |  |
| 74HC245PW   | –40 °C to +125 °C | TSSOP20  | plastic thin shrink small outline package; 20 leads; body width 4.4 mm  | SOT360-1 |  |  |  |
| 74HC245DB   | –40 °C to +125 °C | SSOP20   | plastic shrink small outline package; 20 leads;<br>body width 5.3 mm  | SOT339-1 |  |  |  |
| 74HC245BQ   | –40 °C to +125 °C | DHVQFN20 | plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm | SOT764-1 |  |  |  |
| 74HCT245N   | –40 °C to +125 °C | DIP20    | plastic dual in-line package; 20 leads (300 mil)  | SOT146-1 |  |  |  |
| 74HCT245D   | –40 °C to +125 °C | SO20     | plastic small outline package; 20 leads;<br>body width 7.5 mm   | SOT163-1 |  |  |  |
| 74HCT245PW  | –40 °C to +125 °C | TSSOP20  | plastic thin shrink small outline package; 20 leads; body width 4.4 mm  | SOT360-1 |  |  |  |
| 74HCT245DB  | –40 °C to +125 °C | SSOP20   | plastic shrink small outline package; 20 leads;<br>body width 5.3 mm  | SOT339-1 |  |  |  |
| 74HCT245BQ  | –40 °C to +125 °C | DHVQFN20 | plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5\times4.5\times0.85$ mm     | SOT764-1 |  |  |  |

## 5. Functional diagram



## 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 3: Pin description

| Pin description |  |
|-----------------|--|
| Pin             | Description                              |
| 1               | direction control                        |
| 2               | data input/output                        |
| 3               | data input/output                        |
| 4               | data input/output                        |
| 5               | data input/output                        |
| 6               | data input/output                        |
| 7               | data input/output                        |
| 8               | data input/output                        |
| 9               | data input/output                        |
| 10              | ground (0 V)                             |
| 11              | data input/output                        |
| 12              | data input/output                        |
| 13              | data input/output                        |
| 14              | data input/output                        |
| 15              | data input/output                        |
| 16              | data input/output                        |
|                 | Pin  1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 |

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Table 3: Pin description ...continued

| Symbol   | Pin | Description                      |
|----------|-----|----------------------------------|
| B1       | 17  | data input/output                |
| B0       | 18  | data input/output                |
| ŌĒ       | 19  | output enable input (active LOW) |
| $V_{CC}$ | 20  | supply voltage                   |

## 7. Functional description

### 7.1 Function table

Table 4: Function table [1]

| Input I |     | Input/output |       |  |  |
|---------|-----|--------------|-------|--|--|
| OE      | DIR | An           | Bn    |  |  |
| L       | L   | A = B        | input |  |  |
| L       | Н   | input        | B = A |  |  |
| Н       | X   | Z            | Z     |  |  |

<sup>[1]</sup> H = HIGH voltage level;

## 8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter   | Conditions  |            | Min  | Max  | Unit |
|----------------------|---|---|------------|------|------|------|
| $V_{CC}$             | supply voltage                                    |   |            | -0.5 | +7   | V    |
| I <sub>IK</sub>      | input diode current                               | $V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$       |            | -    | ±20  | mΑ   |
| I <sub>OK</sub>      | output diode current                              | $V_O < -0.5 \text{ V or} $<br>$V_O > V_{CC} + 0.5 \text{ V} $ |            | -    | ±20  | mA   |
| I <sub>O</sub>       | output source or sink current                     | $V_O = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$             |            | -    | ±35  | mA   |
| $I_{CC}$ , $I_{GND}$ | V <sub>CC</sub> or GND current                    |   |            | -    | ±70  | mΑ   |
| T <sub>stg</sub>     | storage temperature                               |   |            | -65  | +150 | °C   |
| P <sub>tot</sub>     | total power dissipation                           |   | <u>[1]</u> |      |      |      |
|                      | DIP20 package                                     |   |            | -    | 750  | mW   |
|                      | SO20, SSOP20,<br>TSSOP20 and<br>DHVQFN20 packages |   |            | -    | 500  | mW   |

<sup>[1]</sup> For DIP20 packages: above 70 °C,  $P_{tot}$  derates linearly with 12 mW/K.

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L = LOW voltage level;

X = don't care:

Z = high-impedance OFF-state.

For SO20 packages: above 70  $^{\circ}\text{C},\,\text{P}_{\text{tot}}$  derates linearly with 8 mW/K.

For SSOP20 and TSSOP20 packages: above 60  $^{\circ}$ C, Ptot derates linearly with 5.5 mW/K.

For DHVQFN20 packages: above 60 °C, Ptot derates linearly with 4.5 mW/K.

## 9. Recommended operating conditions

Table 6: Recommended operating conditions

|                                 |                           | 3 11 3                   |     |     |          |      |  |  |  |
|---------------------------------|---------------------------|--------------------------|-----|-----|----------|------|--|--|--|
| Symbol                          | Parameter                 | Conditions               | Min | Тур | Max      | Unit |  |  |  |
| Type 74H                        | Гуре 74HC245              |                          |     |     |          |      |  |  |  |
| V <sub>CC</sub>                 | supply voltage            |                          | 2.0 | 5.0 | 6.0      | V    |  |  |  |
| VI                              | input voltage             |                          | 0   | -   | $V_{CC}$ | V    |  |  |  |
| Vo                              | output voltage            |                          | 0   | -   | $V_{CC}$ | V    |  |  |  |
| t <sub>r</sub> , t <sub>f</sub> | input rise and fall       | $V_{CC} = 2.0 \text{ V}$ | -   | -   | 1000     | ns   |  |  |  |
|                                 | times                     | V <sub>CC</sub> = 4.5 V  | -   | 6.0 | 500      | ns   |  |  |  |
|                                 |                           | $V_{CC} = 6.0 \text{ V}$ | -   | -   | 400      | ns   |  |  |  |
| T <sub>amb</sub>                | ambient temperature       | Э                        | -40 | -   | +125     | °C   |  |  |  |
| Type 74H                        | CT245                     |                          |     |     |          |      |  |  |  |
| V <sub>CC</sub>                 | supply voltage            |                          | 4.5 | 5.0 | 5.5      | V    |  |  |  |
| VI                              | input voltage             |                          | 0   | -   | $V_{CC}$ | V    |  |  |  |
| Vo                              | output voltage            |                          | 0   | -   | $V_{CC}$ | V    |  |  |  |
| t <sub>r</sub> , t <sub>f</sub> | input rise and fall times | $V_{CC} = 4.5 \text{ V}$ | -   | 6.0 | 500      | ns   |  |  |  |
| T <sub>amb</sub>                | ambient temperature       | Э                        | -40 | -   | +125     | °C   |  |  |  |
|                                 |                           |                          |     |     |          |      |  |  |  |

## 10. Static characteristics

Table 7: Static characteristics type 74HC245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                | Parameter                 | Conditions  | Min  | Тур  | Max  | Unit |
|-----------------------|---------------------------|---|------|------|------|------|
| T <sub>amb</sub> = 25 | °C                        |   |      |      |      |      |
| V <sub>IH</sub>       | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V                           | 1.5  | 1.2  | -    | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V                           | 3.15 | 2.4  | -    | V    |
|                       |                           | V <sub>CC</sub> = 6.0 V                           | 4.2  | 3.2  | -    | V    |
| V <sub>IL</sub>       | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V                           | -    | 0.8  | 0.5  | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V                           | -    | 2.1  | 1.35 | V    |
|                       |                           | V <sub>CC</sub> = 6.0 V                           | -    | 2.8  | 1.8  | V    |
| V <sub>OH</sub>       | HIGH-level output voltage | $V_I = V_{IH}$ or $V_{IL}$                        |      |      |      |      |
|                       |                           | $I_{O} = -20 \mu A; V_{CC} = 2.0 V$               | 1.9  | 2.0  | -    | V    |
|                       |                           | $I_{O} = -20 \mu A$ ; $V_{CC} = 4.5 V$            | 4.4  | 4.5  | -    | V    |
|                       |                           | $I_{O} = -20 \mu A; V_{CC} = 6.0 V$               | 5.9  | 6.0  | -    | V    |
|                       |                           | $I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | 3.98 | 4.32 | -    | V    |
|                       |                           | $I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$ | 5.48 | 5.81 | -    | V    |

 Table 7:
 Static characteristics type 74HC245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                 | Conditions   | Min  | Тур  | Max  | Uni |
|----------------------|---------------------------|--|------|------|------|-----|
| V <sub>OL</sub>      | LOW-level output voltage  | $V_I = V_{IH}$ or $V_{IL}$   |      |      |      |     |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 2.0 V$   | -    | 0    | 0.1  | V   |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 4.5 V$   | -    | 0    | 0.1  | V   |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$                                       | -    | 0    | 0.1  | V   |
|                      |                           | $I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                               | -    | 0.15 | 0.26 | V   |
|                      |                           | $I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$                                 | -    | 0.16 | 0.26 | V   |
| LI                   | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$                                | -    | -    | ±0.1 | μΑ  |
| oz                   | OFF-state output current  | $V_{I}$ = $V_{IH}$ or $V_{IL}$ ; $V_{O}$ = $V_{CC}$ or GND; $V_{CC}$ = 6.0 $V$ | -    | -    | ±0.5 | μΑ  |
| СС                   | quiescent supply current  | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$                   | -    | -    | 8.0  | μΑ  |
| Cı                   | input capacitance         |  | -    | 3.5  | -    | pF  |
| C <sub>I/O</sub>     | input/output capacitance  |  | -    | 10   | -    | pF  |
| $\Gamma_{amb} = -40$ | 0 °C to +85 °C            |  |      |      |      |     |
| V <sub>IH</sub>      | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | -    | -    | V   |
|                      |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | -    | -    | V   |
|                      |                           | V <sub>CC</sub> = 6.0 V  | 4.2  | -    | -    | V   |
| V <sub>IL</sub>      | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -    | -    | 0.5  | V   |
|                      |                           | V <sub>CC</sub> = 4.5 V  | -    | -    | 1.35 | V   |
|                      |                           | V <sub>CC</sub> = 6.0 V  | -    | -    | 1.8  | V   |
| √oн                  | HIGH-level output voltage | $V_I = V_{IH}$ or $V_{IL}$   |      |      |      |     |
|                      |                           | $I_{O} = -20 \mu A; V_{CC} = 2.0 V$  | 1.9  | -    | -    | V   |
|                      |                           | $I_{O} = -20 \mu A; V_{CC} = 4.5 V$  | 4.4  | -    | -    | V   |
|                      |                           | $I_{O} = -20 \mu A; V_{CC} = 6.0 V$  | 5.9  | -    | -    | V   |
|                      |                           | $I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                              | 3.84 | -    | -    | V   |
|                      |                           | $I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$                              | 5.34 | -    | -    | V   |
| $V_{OL}$             | LOW-level output voltage  | $V_I = V_{IH}$ or $V_{IL}$   |      |      |      |     |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 2.0 V$   | -    | -    | 0.1  | V   |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 4.5 V$   | -    | -    | 0.1  | V   |
|                      |                           | $I_O = 20 \mu A; V_{CC} = 6.0 V$   | -    | -    | 0.1  | V   |
|                      |                           | $I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                               | -    | -    | 0.33 | V   |
|                      |                           | $I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$                               | -    | -    | 0.33 | V   |
| ы                    | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$                                | -    | -    | ±1.0 | μΑ  |
| OZ                   | OFF-state output current  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$   | -    | -    | ±5.0 | μΑ  |
| cc                   | quiescent supply current  | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$                   | -    | -    | 80   | μΑ  |
| $\Gamma_{amb} = -40$ | ) °C to +125 °C           |  |      |      |      |     |
| V <sub>IH</sub>      | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | -    | -    | V   |
|                      |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | -    | -    | V   |
|                      |                           | $V_{CC} = 6.0 \text{ V}$   | 4.2  | -    | -    | V   |



At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                 | Conditions   | Min | Тур | Max   | Unit |
|-----------------|---------------------------|--|-----|-----|-------|------|
| $V_{IL}$        | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -   | -   | 0.5   | V    |
|                 |                           | V <sub>CC</sub> = 4.5 V  | -   | -   | 1.35  | V    |
|                 |                           | V <sub>CC</sub> = 6.0 V  | -   | -   | 1.8   | V    |
| V <sub>OH</sub> | HIGH-level output voltage | $V_I = V_{IH}$ or $V_{IL}$   |     | -   |       |      |
|                 |                           | $I_{O} = -20 \mu A; V_{CC} = 2.0 V$  | 1.9 | -   | -     | V    |
|                 |                           | $I_{O} = -20 \mu A; V_{CC} = 4.5 V$  | 4.4 | -   | -     | V    |
|                 |                           | $I_{O} = -20 \mu A; V_{CC} = 6.0 V$  | 5.9 | -   | -     | V    |
|                 |                           | $I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                            | 3.7 | -   | -     | V    |
|                 |                           | $I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$                            | 5.2 | -   | -     | V    |
| V <sub>OL</sub> | LOW-level output voltage  | $V_I = V_{IH}$ or $V_{IL}$   |     | -   |       |      |
|                 |                           | $I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$                                     | -   | -   | 0.1   | V    |
|                 |                           | $I_O = 20 \mu A; V_{CC} = 4.5 V$   | -   | -   | 0.1   | V    |
|                 |                           | $I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$                                     | -   | -   | 0.1   | V    |
|                 |                           | $I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$                               | -   | -   | 0.4   | V    |
|                 |                           | $I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$                               | -   | -   | 0.4   | V    |
| I <sub>LI</sub> | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$                              | -   | -   | ±1.0  | μΑ   |
| l <sub>OZ</sub> | OFF-state output current  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$ | -   | -   | ±10.0 | μΑ   |
| I <sub>CC</sub> | quiescent supply current  | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 6.0 \text{ V}$              | -   | -   | 160   | μΑ   |

## Table 8: Static characteristics type 74HCT245

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                | Parameter                 | Conditions  | Min  | Тур  | Max  | Unit |
|-----------------------|---------------------------|---|------|------|------|------|
| T <sub>amb</sub> = 25 | °C                        |   |      |      |      |      |
| V <sub>IH</sub>       | HIGH-level input voltage  | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$  | 2.0  | 1.6  | -    | V    |
| V <sub>IL</sub>       | LOW-level input voltage   | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$  | -    | 1.2  | 0.8  | V    |
| $V_{OH}$              | HIGH-level output voltage | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$   |      |      |      |      |
|                       |                           | $I_{O} = -20 \mu\text{A}$   | 4.4  | 4.5  | -    | V    |
|                       |                           | $I_O = -6 \text{ mA}$   | 3.98 | 4.32 | -    | V    |
| V <sub>OL</sub>       | LOW-level output voltage  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$   |      |      |      |      |
|                       |                           | I <sub>O</sub> = 20 μA  | -    | 0    | 0.1  | V    |
|                       |                           | $I_{O} = 6.0 \text{ mA}$  | -    | 0.15 | 0.26 | V    |
| ILI                   | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$   | -    | -    | ±0.1 | μΑ   |
| l <sub>OZ</sub>       | OFF-state output current  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5 \text{ V}$ ;<br>$V_O = V_{CC}$ or GND per input pin;<br>other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ | -    | -    | ±0.5 | μΑ   |
| I <sub>CC</sub>       | quiescent supply current  | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$   | -    | -    | 8.0  | μΑ   |

 Table 8:
 Static characteristics type 74HCT245 ...continued

At recommended operating conditions: voltages are referenced to GND (ground = 0 V).

| Symbol                | Parameter   | Conditions   | Min  | Тур | Max  | Uni |
|-----------------------|---|--|------|-----|------|-----|
| Δl <sub>CC</sub>      | additional quiescent supply current per input pin | $V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A                                  |      |     |      |     |
|                       | An or Bn inputs                                   |  | -    | 40  | 144  | μΑ  |
|                       | OE input  |  | -    | 150 | 540  | μΑ  |
|                       | DIR input   |  | -    | 90  | 324  | μΑ  |
| Cı                    | input capacitance                                 |  | -    | 3.5 | -    | pF  |
| C <sub>I/O</sub>      | input/output capacitance                          |  | -    | 10  | -    | pF  |
| T <sub>amb</sub> = -4 | 0 °C to +85 °C                                    |  |      |     |      |     |
| $V_{IH}$              | HIGH-level input voltage                          | V <sub>CC</sub> = 4.5 V to 5.5 V   | 2.0  | -   | -    | V   |
| V <sub>IL</sub>       | LOW-level input voltage                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | -    | -   | 0.8  | V   |
| V <sub>OH</sub>       | HIGH-level output voltage                         | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |     |      |     |
|                       |   | $I_O = -20 \mu A$  | 4.4  | -   | -    | V   |
|                       |   | $I_O = -6 \text{ mA}$  | 3.84 | -   | -    | V   |
| V <sub>OL</sub>       | LOW-level output voltage                          | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |     |      |     |
|                       |   | I <sub>O</sub> = 20 μA   | -    | -   | 0.1  | V   |
|                       |   | I <sub>O</sub> = 6.0 mA  | -    | -   | 0.33 | V   |
| ILI                   | input leakage current                             | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$  | -    | -   | ±1.0 | μΑ  |
| l <sub>OZ</sub>       | OFF-state output current                          | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V;<br>$V_O = V_{CC}$ or GND per input pin;<br>other inputs at $V_{CC}$ or GND; $I_O = 0$ A | -    | -   | ±5.0 | μΑ  |
| I <sub>CC</sub>       | quiescent supply current                          | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -   | 80   | μΑ  |
| Δl <sub>CC</sub>      | additional quiescent supply current per input pin | $V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A                                  |      |     |      |     |
|                       | An or Bn inputs                                   |  | -    | -   | 180  | μΑ  |
|                       | OE input  |  | -    | -   | 675  | μΑ  |
|                       | DIR input   |  | -    | -   | 405  | μΑ  |
| T <sub>amb</sub> = -4 | 0 °C to +125 °C                                   |  |      |     |      |     |
| V <sub>IH</sub>       | HIGH-level input voltage                          | V <sub>CC</sub> = 4.5 V to 5.5 V   | 2.0  | -   | -    | V   |
| V <sub>IL</sub>       | LOW-level input voltage                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | -    | -   | 8.0  | V   |
| V <sub>OH</sub>       | HIGH-level output voltage                         | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |     |      |     |
|                       |   | I <sub>O</sub> = -20 μA  | 4.4  | -   | -    | V   |
|                       |   | $I_O = -6 \text{ mA}$  | 3.7  | -   | -    | V   |
| V <sub>OL</sub>       | LOW-level output voltage                          | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$  |      |     |      |     |
|                       |   | I <sub>O</sub> = 20 μA   | -    | -   | 0.1  | V   |
|                       |   | I <sub>O</sub> = 6.0 mA  | -    | -   | 0.4  | V   |
| ILI                   | input leakage current                             | $V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$  | -    | -   | ±1.0 | μΑ  |
| I <sub>OZ</sub>       | OFF-state output current                          | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V;<br>$V_O = V_{CC}$ or GND per input pin;<br>other inputs at $V_{CC}$ or GND; $I_O = 0$ A | -    | -   | ±10  | μA  |

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At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter   | Conditions   | Min | Тур | Max | Unit |
|-----------------|---|--|-----|-----|-----|------|
| I <sub>CC</sub> | quiescent supply current                          | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -   | -   | 160 | μΑ   |
| $\Delta I_{CC}$ | additional quiescent supply current per input pin | $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$ |     |     |     |      |
|                 | An or Bn inputs                                   |  | -   | -   | 196 | μΑ   |
|                 | OE input  |  | -   | -   | 735 | μΑ   |
|                 | DIR input   |  | -   | -   | 441 | μΑ   |

## 11. Dynamic characteristics

Table 9: Dynamic characteristics type 74HC245

GND = 0 V; test circuit see Figure 7.

| Symbol                              | Parameter  | Conditions                                    | Min   | Тур | Max | Unit |
|-------------------------------------|--|---|-------|-----|-----|------|
| T <sub>amb</sub> = 25               | °C   |   |       |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn   | see Figure 5                                  |       |     |     |      |
|                                     | to An  | V <sub>CC</sub> = 2.0 V                       | -     | 25  | 90  | ns   |
|                                     |  | V <sub>CC</sub> = 4.5 V                       | -     | 9   | 18  | ns   |
|                                     |  | $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$ | -     | 7   | -   | ns   |
|                                     |  | $V_{CC} = 6.0 \text{ V}$                      | -     | 7   | 15  | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time OE to   | see Figure 6                                  |       |     |     |      |
|                                     | An or OE to Bn   | V <sub>CC</sub> = 2.0 V                       | -     | 30  | 150 | ns   |
|                                     |  | V <sub>CC</sub> = 4.5 V                       | -     | 11  | 30  | ns   |
|                                     |  | V <sub>CC</sub> = 6.0 V                       | -     | 9   | 26  | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | PHZ, tPLZ 3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn | see Figure 6                                  |       |     |     |      |
| YPHZ; YPLZ                          |  | V <sub>CC</sub> = 2.0 V                       | -     | 41  | 150 | ns   |
|                                     |  | V <sub>CC</sub> = 4.5 V                       | -     | 15  | 30  | ns   |
|                                     |  | $V_{CC} = 6.0 \text{ V}$                      | -     | 12  | 26  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time   | see Figure 5                                  |       |     |     |      |
|                                     |  | V <sub>CC</sub> = 2.0 V                       | -     | 14  | 60  | ns   |
|                                     |  | V <sub>CC</sub> = 4.5 V                       | -     | 5   | 12  | ns   |
|                                     |  | V <sub>CC</sub> = 6.0 V                       | -     | 4   | 10  | ns   |
| $C_{PD}$                            | power dissipation capacitance per transceiver  | $V_I = GND$ to $V_{CC}$                       | [1] - | 30  | -   | pF   |
| T <sub>amb</sub> = -40              | °C to +85 °C   |   |       |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn   | see Figure 5                                  |       |     |     |      |
|                                     | to An  | V <sub>CC</sub> = 2.0 V                       | -     | -   | 115 | ns   |
|                                     |  | V <sub>CC</sub> = 4.5 V                       | -     | -   | 23  | ns   |
|                                     |  | V <sub>CC</sub> = 6.0 V                       | -     | -   | 20  | ns   |

**Table 9: Dynamic characteristics type 74HC245** ...continued GND = 0 V; test circuit see Figure 7.

| Symbol                              | Parameter   | Conditions              | Min | Тур | Max | Unit |
|-------------------------------------|---|-------------------------|-----|-----|-----|------|
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time OE to                      | see Figure 6            |     |     |     |      |
|                                     | An or OE to Bn  | V <sub>CC</sub> = 2.0 V | -   | -   | 190 | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 38  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 33  | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | 3-state output disable time $\overline{\text{OE}}$ to | see Figure 6            |     |     |     |      |
|                                     | An or OE to Bn  | V <sub>CC</sub> = 2.0 V | -   | -   | 190 | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 38  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 33  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time                                | see Figure 5            |     |     |     |      |
|                                     |   | V <sub>CC</sub> = 2.0 V | -   | -   | 75  | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 15  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 13  | ns   |
| T <sub>amb</sub> = -40              | °C to +125 °C   |                         |     |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn                      | see Figure 5            |     |     |     |      |
|                                     | to An   | V <sub>CC</sub> = 2.0 V | -   | -   | 135 | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 27  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 23  | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time OE to                      | see Figure 6            |     |     |     |      |
|                                     | An or $\overline{OE}$ to Bn                           | V <sub>CC</sub> = 2.0 V | -   | -   | 225 | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 45  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 38  | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | 3-state output disable time OE to                     | see Figure 6            |     |     |     |      |
|                                     | An or OE to Bn  | V <sub>CC</sub> = 2.0 V | -   | -   | 225 | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 45  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 38  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time                                | see Figure 5            |     |     |     |      |
|                                     |   | V <sub>CC</sub> = 2.0 V | -   | -   | 90  | ns   |
|                                     |   | V <sub>CC</sub> = 4.5 V | -   | -   | 18  | ns   |
|                                     |   | V <sub>CC</sub> = 6.0 V | -   | -   | 15  | ns   |

<sup>[1]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

Table 10: Dynamic characteristics type 74HCT245

GND = 0 V; test circuit see Figure 7.

| Symbol                              | Parameter  | Conditions                                     | Min          | Тур | Max | Unit |
|-------------------------------------|--|--|--------------|-----|-----|------|
| T <sub>amb</sub> = 25               | C  |  |              |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn   | see Figure 5                                   |              |     |     |      |
|                                     | to An  | V <sub>CC</sub> = 4.5 V                        | -            | 12  | 22  | ns   |
|                                     |  | $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$  | -            | 10  | -   | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn  | V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>   | -            | 16  | 30  | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | 3-state output disable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn | V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>   | -            | 16  | 30  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time   | V <sub>CC</sub> = 4.5 V; see Figure 5          | -            | 5   | 12  | ns   |
| C <sub>PD</sub>                     | power dissipation capacitance per transceiver  | $V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$ | <u>[1]</u> - | 30  | -   | pF   |
| T <sub>amb</sub> = -40              | °C to +85 °C   |  |              |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn to An   | V <sub>CC</sub> = 4.5 V; see <u>Figure 5</u>   | -            | -   | 28  | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn  | V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>   | -            | -   | 38  | ns   |
| $t_{PHZ}$ , $t_{PLZ}$               | 3-state output disable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn | V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>   | -            | -   | 38  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time   | V <sub>CC</sub> = 4.5 V; see Figure 5          | -            | -   | 15  | ns   |
| T <sub>amb</sub> = -40              | °C to +125 °C  |  |              |     |     |      |
| t <sub>PHL</sub> , t <sub>PLH</sub> | propagation delay An to Bn or Bn to An   | V <sub>CC</sub> = 4.5 V; see <u>Figure 5</u>   | -            | -   | 33  | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | 3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn                | $V_{CC} = 4.5 \text{ V}$ ; see Figure 6        | -            | -   | 45  | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | 3-state output disable time $\overline{\text{OE}}$ to An or $\overline{\text{OE}}$ to Bn | $V_{CC} = 4.5 \text{ V}$ ; see Figure 6        | -            | -   | 45  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time   | V <sub>CC</sub> = 4.5 V; see Figure 5          | -            | -   | 18  | ns   |
| t <sub>THL</sub> , t <sub>TLH</sub> | output transition time   | V <sub>CC</sub> = 4.5 V; see <u>Figure 5</u>   | -            | -   | 18  | ns   |

<sup>[1]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

## 12. Waveforms

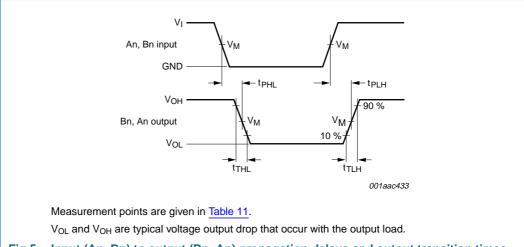
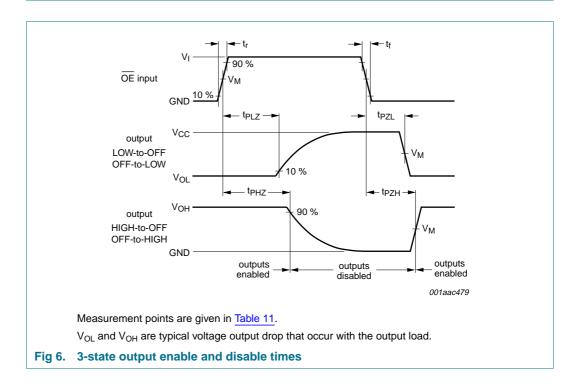


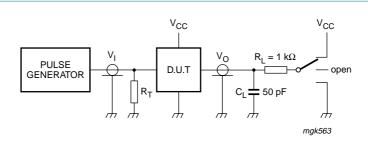
Fig 5. Input (An, Bn) to output (Bn, An) propagation delays and output transition times



**Table 11: Measurement points** 

| Туре     | Input              | Output             |
|----------|--------------------|--------------------|
|          | V <sub>M</sub>     | V <sub>M</sub>     |
| 74HC245  | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> |
| 74HCT245 | 1.3 V              | 1.3 V              |

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Test data is given in Table 12.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistor.

Fig 7. Load circuitry for switching times

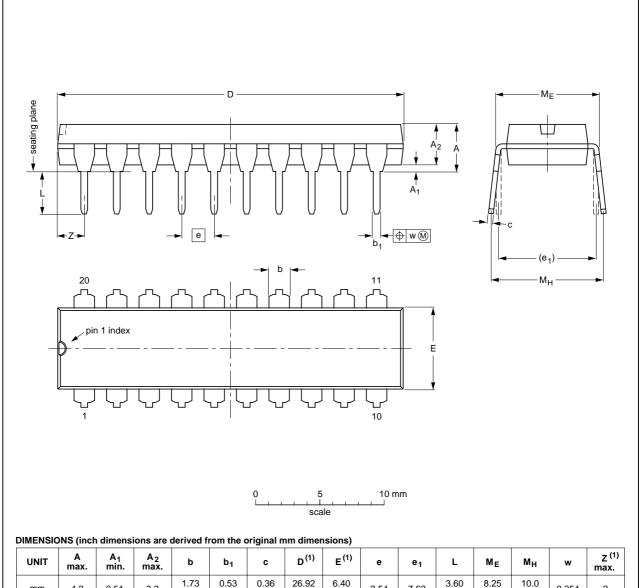
Table 12: Test data

| Туре     | Input    |                                 | Test                                | Test                                |                                     |  |  |  |  |
|----------|----------|---------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|--|--|--|--|
|          | VI       | t <sub>r</sub> , t <sub>f</sub> | t <sub>PHL</sub> , t <sub>PLH</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> |  |  |  |  |
| 74HC245  | $V_{CC}$ | 6 ns                            | open                                | GND                                 | V <sub>CC</sub>                     |  |  |  |  |
| 74HCT245 | 3 V      | 6 ns                            | open                                | GND                                 | V <sub>CC</sub>                     |  |  |  |  |

## 13. Package outline

## DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



| UNIT   | A<br>max. | A <sub>1</sub><br>min. | A <sub>2</sub><br>max. | b              | b <sub>1</sub> | С              | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | e <sub>1</sub> | L            | ME           | Мн           | w     | Z <sup>(1)</sup><br>max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|--------------|--------------|-------|--------------------------|
| mm     | 4.2       | 0.51                   | 3.2                    | 1.73<br>1.30   | 0.53<br>0.38   | 0.36<br>0.23   | 26.92<br>26.54   | 6.40<br>6.22     | 2.54 | 7.62           | 3.60<br>3.05 | 8.25<br>7.80 | 10.0<br>8.3  | 0.254 | 2                        |
| inches | 0.17      | 0.02                   | 0.13                   | 0.068<br>0.051 | 0.021<br>0.015 | 0.014<br>0.009 | 1.060<br>1.045   | 0.25<br>0.24     | 0.1  | 0.3            | 0.14<br>0.12 | 0.32<br>0.31 | 0.39<br>0.33 | 0.01  | 0.078                    |

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

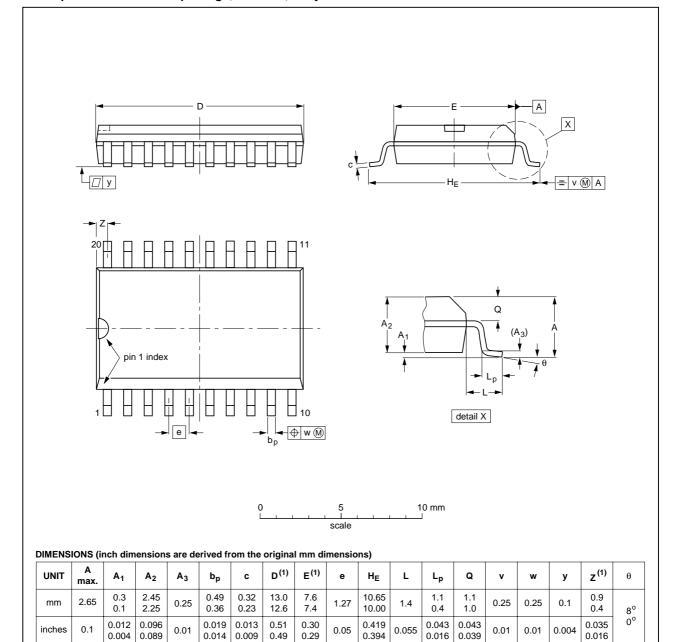
| VERSION         IEC         JEDEC         JEITA         PROJECTION           SOT146-1         MS-001         SC-603 | OUTLINE  |     | REFER  | ENCES  | EUROPEAN   | ISSUE DATE                      |
|---|----------|-----|--------|--------|------------|---------------------------------|
| SO(146-1) $MS-001$ $SC-603$ $++++++++++++++++++++++++++++++++++++$  | VERSION  | IEC | JEDEC  | JEITA  | PROJECTION | ISSUE DATE                      |
| 03-02-13  | SOT146-1 |     | MS-001 | SC-603 |            | <del>99-12-27</del><br>03-02-13 |

Fig 8. Package outline SOT146-1 (DIP20)

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### SO20: plastic small outline package; 20 leads; body width 7.5 mm

### SOT163-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

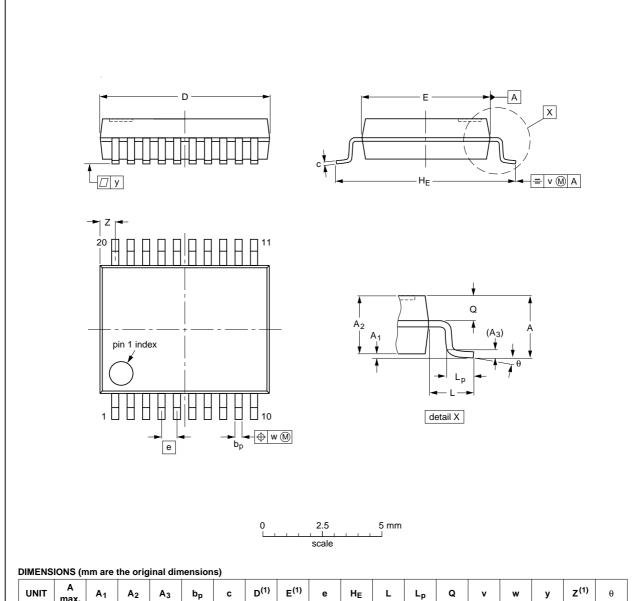
| OUTLINE  |        | REFER  | ENCES | EUROPEAN   | ISSUE DATE                      |
|----------|--------|--------|-------|------------|---------------------------------|
| VERSION  | IEC    | JEDEC  | JEITA | PROJECTION | ISSUE DATE                      |
| SOT163-1 | 075E04 | MS-013 |       |            | <del>99-12-27</del><br>03-02-19 |

Fig 9. Package outline SOT163-1 (SO20)

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## SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



| - |      |           |                | 3              |                |              | -,           |                  |                  |      |            |      |              |            |     |      |     |                  |          |
|---|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|------------------|------|------------|------|--------------|------------|-----|------|-----|------------------|----------|
|   | UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | bp           | С            | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | HE         | L    | Lp           | Q          | v   | w    | у   | Z <sup>(1)</sup> | θ        |
|   | mm   | 2         | 0.21<br>0.05   | 1.80<br>1.65   | 0.25           | 0.38<br>0.25 | 0.20<br>0.09 | 7.4<br>7.0       | 5.4<br>5.2       | 0.65 | 7.9<br>7.6 | 1.25 | 1.03<br>0.63 | 0.9<br>0.7 | 0.2 | 0.13 | 0.1 | 0.9<br>0.5       | 8°<br>0° |

#### Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

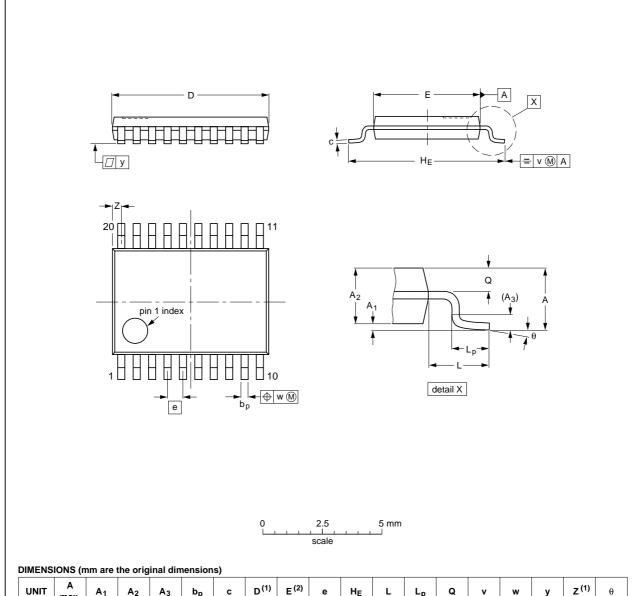
| OUTLINE  |     | REFER  | ENCES | EUROPEAN   | ISSUE DATE                      |
|----------|-----|--------|-------|------------|---------------------------------|
| VERSION  | IEC | JEDEC  | JEITA | PROJECTION | ISSUE DATE                      |
| SOT339-1 |     | MO-150 |       |            | <del>99-12-27</del><br>03-02-19 |

Fig 10. Package outline SOT339-1 (SSOP20)

9397 750 14502

### TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



| = |      |           |                |                |                |              |            |                  |                  |      |            |   |              |            |     |      |     |                  |          |
|---|------|-----------|----------------|----------------|----------------|--------------|------------|------------------|------------------|------|------------|---|--------------|------------|-----|------|-----|------------------|----------|
|   | UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | bp           | С          | D <sup>(1)</sup> | E <sup>(2)</sup> | е    | HE         | L | Lp           | Q          | v   | w    | у   | Z <sup>(1)</sup> | θ        |
|   | mm   | 1.1       | 0.15<br>0.05   | 0.95<br>0.80   | 0.25           | 0.30<br>0.19 | 0.2<br>0.1 | 6.6<br>6.4       | 4.5<br>4.3       | 0.65 | 6.6<br>6.2 | 1 | 0.75<br>0.50 | 0.4<br>0.3 | 0.2 | 0.13 | 0.1 | 0.5<br>0.2       | 8°<br>0° |

### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE  |     | REFER  | EUROPEAN | ISSUE DATE |            |                                 |  |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|
| VERSION  | IEC | JEDEC  | JEITA    |            | PROJECTION | ISSUE DATE                      |  |
| SOT360-1 |     | MO-153 |          |            |            | <del>99-12-27</del><br>03-02-19 |  |

Fig 11. Package outline SOT360-1 (TSSOP20)

9397 750 14502

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

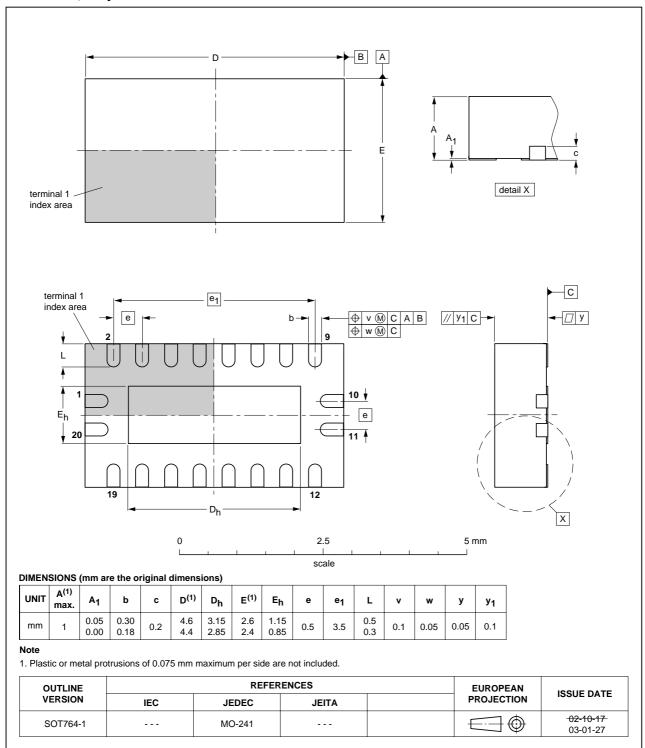


Fig 12. Package outline SOT764-1 (DHVQFN20)

9397 750 14502



## 14. Revision history

## Table 13: Revision history

| Document ID       | Release<br>date  | Data sheet status                            | Change notice | Doc. number    | Supersedes              |  |  |  |  |
|-------------------|--|--|---------------|----------------|-------------------------|--|--|--|--|
| 74HC_HCT245_3     | 20050131   | Product data sheet                           | -             | 9397 750 14502 | 74HC_HCT245_CNV_2       |  |  |  |  |
| Modifications:    | <ul> <li>The format of this data sheet is redesigned to comply with the new presentation and<br/>information standard of Philips Semiconductors</li> </ul> |  |               |                |                         |  |  |  |  |
|                   |  | "Ordering information in modified to include |               |                | and Section 13 "Package |  |  |  |  |
| 74HC_HCT245_CNV_2 | 19930930   | Product specification                        | -             | -              | -                       |  |  |  |  |



| Level | Data sheet status [1] | Product status [2] [3] | Definition   |
|-------|-----------------------|------------------------|--|
| I     | Objective data        | Development            | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.  |
| II    | Preliminary data      | Qualification          | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.             |
| III   | Product data          | Production             | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

- [1] Please consult the most recently issued data sheet before initiating or completing a design.
- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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For sales office addresses, send an email to: <a href="mailto:sales.addresses@www.semiconductors.philips.com">sales.addresses@www.semiconductors.philips.com</a>

# 74HC245; 74HCT245

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Octal bus tranceiver; 3-state

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